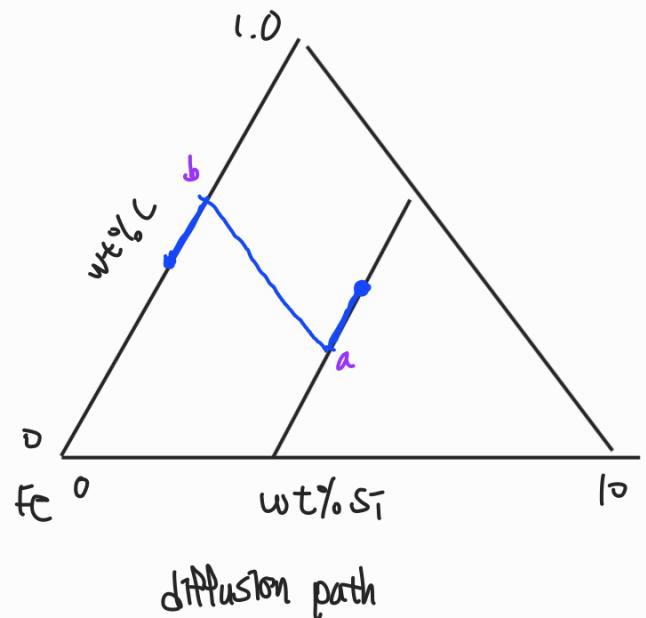
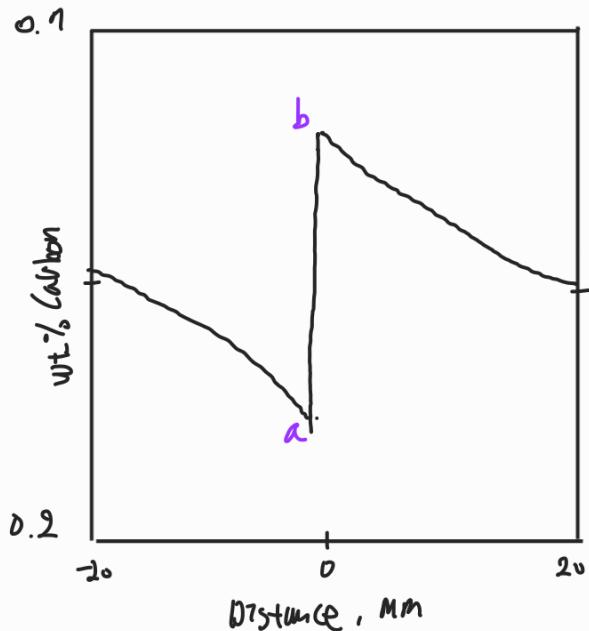


phase transformations problem set #3

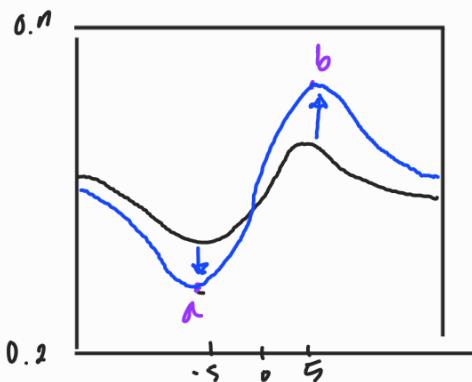
2022.10.2 이마태

1. (1) 13 days annealing time

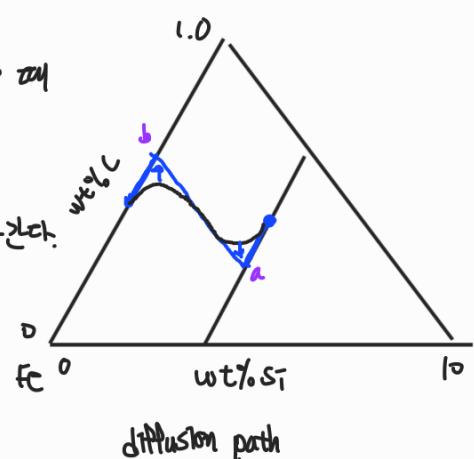


(2) Si 가 10mm 위치의 non-zero gradient 일 때.

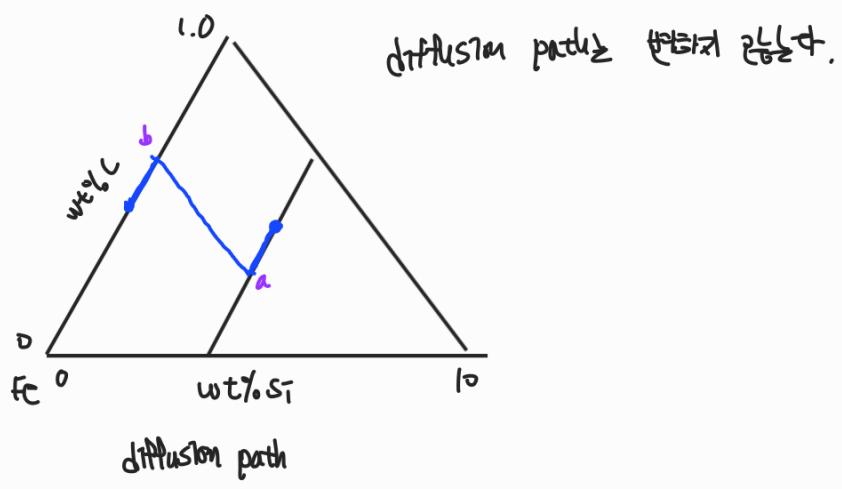
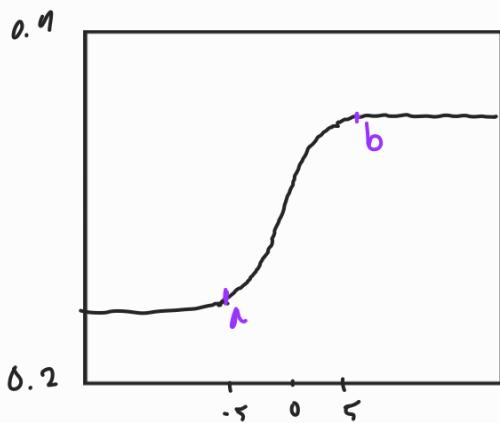
i) C 가 초기 조성에서 13일 정도 카보를 때



Si 조성 gradient 가 생겼을 때
diffusion path가 처음에는
검정을 따라 가지만 시간이
지남에 따라 표면을 따라간다.

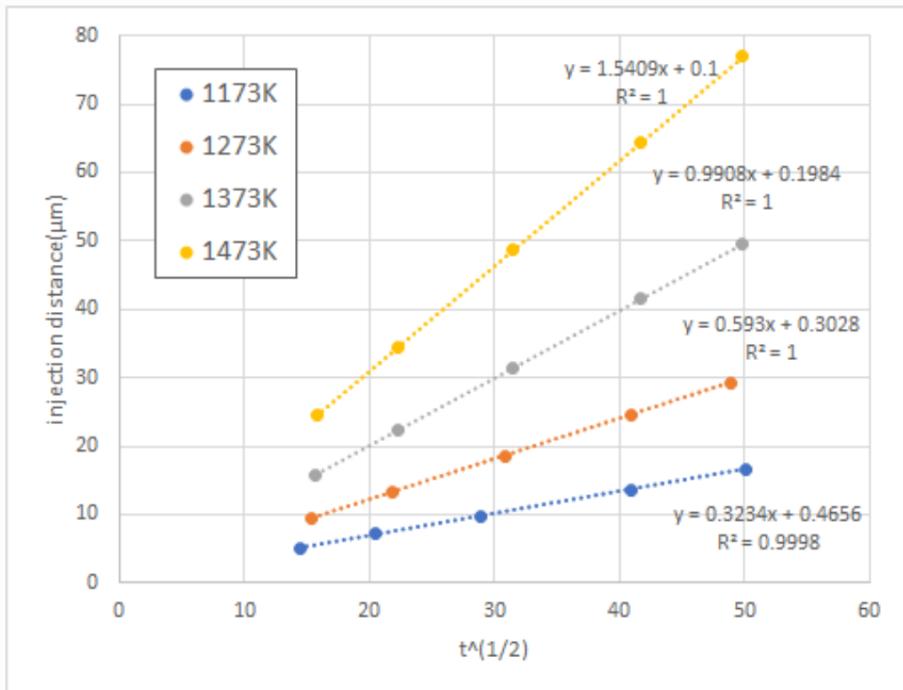


ii) Si 가 non-zero gradient 가 되어 순간면은 C 를 diffusion 했을 때

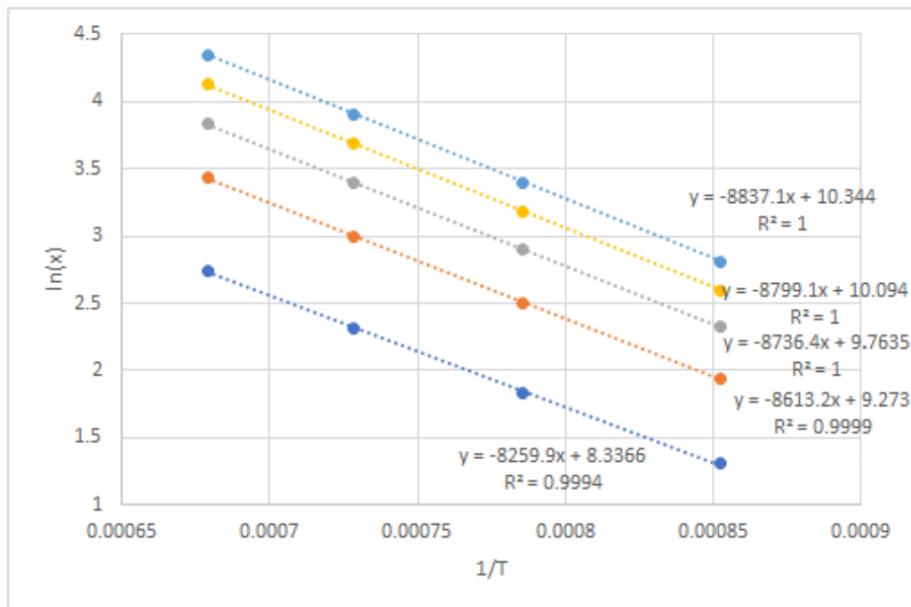


2.

(a)

injection distance = $\propto 21 \cdot \frac{1}{\sqrt{T}}$ $\propto \sqrt{T}$

(b)

 $\ln \alpha = a + b \times \frac{1}{T}$

(c)

$$\alpha = \sqrt{Dt} = \sqrt{D_0 \exp\left(-\frac{Q}{RT}\right)t}$$

$$\ln \alpha = \frac{1}{2} \ln D_0 t - \frac{Q}{2R} \cdot \frac{1}{T}$$

$$Q = -2R \times (b) \text{에서 } \alpha \text{의 } \frac{\partial \ln \alpha}{\partial T}$$

$$= 143817.9 \text{ J}$$

$$\text{포함} (\%) = 2.64 \%$$